

#### **Data Sheet**

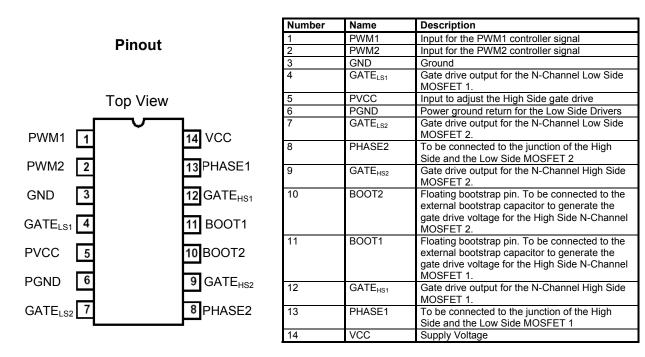
# High speed Driver with bootstrapping for dual Power MOSFETs



#### Features

- Fast rise and fall times for frequencies up to 2 MHz
- Capable of sinking more than 4 A peak current for lowest switching losses
- Charges the High Side and Low Side MOSFET's gate to 6..12 V according to PVCC setting.
- Adjustable High Side and Low Side MOSFET gate drive voltage via PVCC pin for optimizing ON losses and gate drive losses
- Integrates the bootstrap diode for reducing the part count
- Prevents from cross-conducting by adaptive gate drive control
- High voltage rating on Phase node
- Supports shut-down mode for very low quiescent current through three-state input
- Compatible to standard PWM controller ICs (Intersil, Analog Devices)
- Floating High Side MOSFET drive
  - Ideal for multi-phase Desktop CPU supplies on motherboards and VRM's

| Туре     | Package    | Marking | Ordering Code |
|----------|------------|---------|---------------|
| TDA21102 | P-DSO-14-3 | 21102   | Q67042-S4244  |





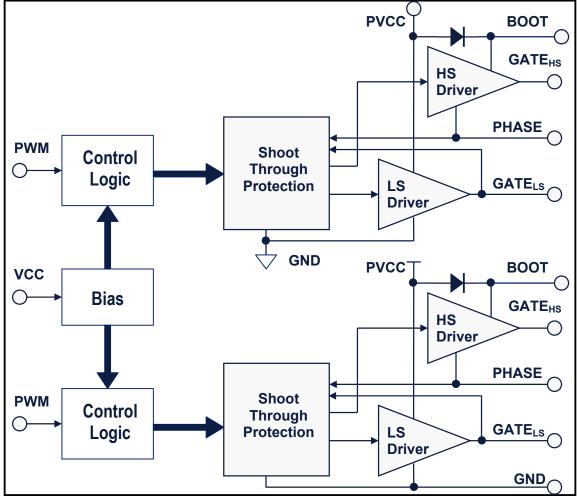
#### **General Description**

The dual high speed driver is designed to drive a wide range of N-Channel low side and N-Channel high side MOSFETs with varying gate charges. It has a small propagation delay from input to output, short rise and fall times and the same pin configuration as the HIP6602B. In addition it provides several protection features as well as a shut down mode for efficiency reasons. The high breakdown voltage makes it suitable for mobile applications.

#### **Target application**

The dual high speed driver is designed to work well in half-bridge type circuits where dual N-Channel MOSFETs are utilized. A circuit designer can fully take advantage of the driver's capabilities in high-efficiency, high-density synchronous DC/DC converters that operate at high switching frequencies, e.g. in multi-phase converters for CPU supplies on motherboards and VRM's but also in motor drive and class-D amplifier type applications.

#### Block Diagram





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#### **Data Sheet**

# Absolute Maximum Ratings At Tj = 25 °C, unless otherwise specified

| Parameter   | Symbol                                    | Va   | lue   | Unit |
|---|---|------|-------|------|
|   |   | Min. | Max.  |      |
| Voltage supplied to 'VCC' pin   | V <sub>VCC</sub>                          | -0.3 | 25    |      |
| Voltage supplied to 'PVCC' pin  | V <sub>PVCC</sub>                         | -0.3 | 25    | V    |
| Voltage supplied to 'PWM' pin   | V <sub>PWM</sub>                          | -0.3 | 5.5   |      |
| Voltage supplied to 'BOOT' pin referenced to 'PHASE'                                | V <sub>BOOT</sub> –<br>V <sub>PHASE</sub> | -0.3 | 25    |      |
| Voltage rating at 'PHASE' pin, DC   | $V_{PHASE}$                               | -1   | 25    |      |
| Voltage rating at 'PHASE' pin, t <sub>pulse_max</sub> =500ns<br>Max Duty Cycle = 2% |   | -20  | 30    |      |
| Junction temperature  | TJ  | -25  | 150   | °C   |
| Storage temperature   | Τs  | -55  | 150   |      |
| ESD Rating; Human Body Model  |   |      | 4     | kV   |
| IEC climatic category; DIN EN 60068-1   |   | 55/1 | 50/56 | -    |

#### **Thermal Characteristic**

| Parameter                            | Symbol | Values |       | Unit |     |
|--------------------------------------|--------|--------|-------|------|-----|
|                                      | -      | Min.   | Тур.  | Max. |     |
| Thermal resistance, junction-case    | Rth-JC |        | 44,7  |      | K/W |
| Thermal resistance, junction-ambient | Rth-JA |        | 116,2 |      |     |

#### **Electrical Characteristic**

At Tj = 25 °C, unless otherwise specified

| Parameter             | Symbol             | Conditions                                 | Values |      |      | Unit |  |
|-----------------------|--------------------|--|--------|------|------|------|--|
|                       | -                  |  | Min.   | Тур. | Max. |      |  |
| Supply Characteristic |                    |  |        |      |      |      |  |
| Bias supply current   | I <sub>VCC</sub>   | f = 1 MHz,                                 |        |      |      |      |  |
|                       |                    | NO LOAD                                    |        | 0.95 | 1.65 |      |  |
|                       |                    | $V_{PVCC} = V_{VCC} = 12 V$                |        |      |      |      |  |
| Quiescent current     | Ivccq              | $1.8~V \leq V_{PWM} \leq 3.0~V$            |        | 0.75 | 3    | mA   |  |
| Power supply current  | I <sub>PVCC</sub>  | f = 1 MHz,                                 |        |      |      |      |  |
|                       |                    | NO LOAD                                    |        | 26   |      |      |  |
|                       |                    | $V_{PVCC} = V_{VCC} = 12 V$                |        |      |      |      |  |
| Under-voltage lockout |                    | V <sub>VCC</sub> rising threshold          | 9.7    | 10.1 | 10.5 | V    |  |
| Under-voltage lockout |                    | V <sub>VCC</sub> falling threshold         | 7.3    | 7.6  | 8.0  | V    |  |
| Input Characteristic  |                    |  |        |      |      |      |  |
| Current in 'PWM' pin  | I <sub>PWM L</sub> | V <sub>PWM</sub> = 0.4 V                   | -80    | 115  | -150 | μA   |  |
| Current in 'PWM' pin  | I <sub>PWM H</sub> | V <sub>PWM</sub> = 4.5 V                   | 120    | 180  | 250  |      |  |
| Shut down window      | VIN SHUT           | t_ <sub>SHUT</sub> > 320 ns                | 1.7    |      | 3.1  | V    |  |
| Shut down hold-off    | t_ <sub>SHUT</sub> | 1.7 V $\leq$ V <sub>PWM</sub> $\leq$ 3.1 V | 100    | 230  | 350  | ns   |  |
| time                  |                    |  |        |      |      |      |  |
| PWM pin open          | V <sub>PWM_0</sub> |  | 1.8    | 2.0  | 2.2  |      |  |



### *CoreControl*<sup>™</sup>

#### **Data Sheet**

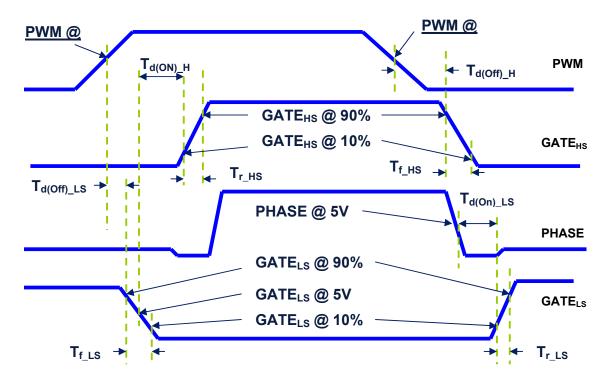
TDA21102

| PWM Low level<br>threshold (falling) | V <sub>PWM_L</sub> |                         | 1.45 | 1.55 |     | V  |
|--------------------------------------|--------------------|-------------------------|------|------|-----|----|
| PWM High level<br>threshold (rising) | V <sub>PWM_H</sub> |                         |      | 3.45 | 3.6 |    |
| Pulse Width High<br>Side             | t_p                | = Pulse with on PWM pin | 40   |      |     | ns |

#### At Tj = 25 °C, unless otherwise specified

| Dynamic Characteristic |                        |                             |  |    |    |    |  |
|------------------------|------------------------|-----------------------------|--|----|----|----|--|
| Turn-on propagation    | t <sub>d(ON)_HS</sub>  |                             |  | 27 | 35 |    |  |
| Delay High Side*       |                        |                             |  |    |    |    |  |
| Turn-off propagation   | $t_{d(OFF)_{HS}}$      |                             |  | 16 | 21 |    |  |
| delay High Side        |                        |                             |  |    |    |    |  |
| Rise time High Side    | t <sub>r_HS</sub>      |                             |  | 20 | 25 |    |  |
| Fall time High Side    | t <sub>f_HS</sub>      | $P_{PVCC} = V_{VCC} = 12 V$ |  | 11 | 20 | ns |  |
| Turn-on propagation    | t <sub>d(ON)_LS</sub>  | C <sub>ISS</sub> = 3000 pF  |  | 20 | 23 |    |  |
| Delay Low Side         |                        |                             |  |    |    |    |  |
| Turn-off propagation   | t <sub>d(OFF)</sub> LS |                             |  | 13 | 20 |    |  |
| delay Low Side         |                        |                             |  |    |    |    |  |
| Rise time Low Side     | t <sub>r_LS</sub>      |                             |  | 22 | 25 |    |  |
| Fall time Low Side     | t <sub>f_LS</sub>      |                             |  | 13 | 20 |    |  |

#### Measurement Timing diagram





# CoreControl TM

#### **Data Sheet**

**Operating Conditions** At Tj = 25 °C, unless otherwise specified

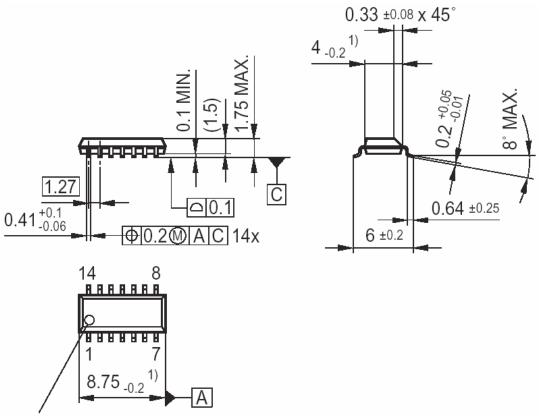
| Parameter                         | Symbol            | Conditions                                      | Values |      |      | Unit |
|-----------------------------------|-------------------|---|--------|------|------|------|
|                                   |                   |   | Min.   | Тур. | Max. |      |
| Voltage supplied to<br>'VCC' pin  | V <sub>VCC</sub>  |   | 10.8   |      | 13.2 | V    |
| Voltage supplied to<br>'PVCC' pin | V <sub>PVCC</sub> |   | 6      |      | 13.2 | V    |
| Input signal transition frequency | f                 |   | 0.1    |      | 2    | MHz  |
| Power dissipation                 | P <sub>TOT</sub>  | T <sub>A</sub> = 25 °C, T <sub>J</sub> = 125 °C |        | 0.9  |      | W    |
| Junction temperature              | ΤJ                |   | -25    |      | 150  | °C   |

#### At Tj = 25 °C, unless otherwise specified

| Parameter       |                  | Conditions                                   | Values |         |        | Unit |
|-----------------|------------------|--|--------|---------|--------|------|
|                 |                  |  | Min.   | Тур.    | Max.   |      |
| Output Characte | ristic High Side | e (HS) and Low Side (LS), (                  | ensure | ed by d | lesign |      |
| Output          | HS; Source       | $P_{PVCC} = V_{VCC} = 12 V$                  |        | 1.2     |        | Ω    |
| Resistance      |                  | $I_{HS_{SRC}} = 2 A$                         |        |         |        |      |
|                 | HS; Sink         | $P_{PVCC} = V_{VCC} = 12 V$                  |        | 1       | 1.5    | Ω    |
|                 | LS; Source       | $P_{PVCC} = V_{VCC} = 12 V$                  |        | 1       |        | Ω    |
|                 |                  | I <sub>HS SRC</sub> = 2 A                    |        |         |        |      |
|                 | LS; Sink         | $P_{PVCC} = V_{VCC} = 12 V$                  |        | 1       | 1.3    | Ω    |
|                 | HS; Source       | $P_{PVCC} = V_{VCC} = 12 V$                  | 4      |         |        |      |
| Peak output-    | HS; Sink         | t_ <sub>P_Hs</sub> / Pulse < 20 ns           | 4      |         |        | А    |
| current         | LS; Source       | t_ <sub>P_LS</sub> / Pulse < 40 ns           | 4      |         |        |      |
|                 | LS; Sink         | D_ <sub>HS</sub> < 2%, D_ <sub>LS</sub> < 4% | 4      |         |        |      |



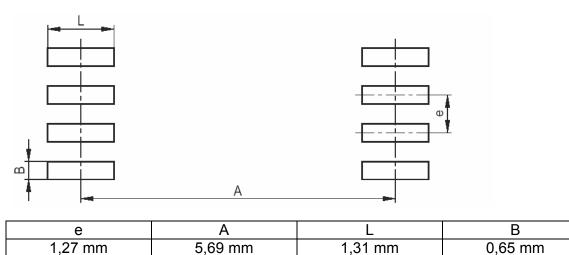
#### Package Drawing P-DSO-14-3



Index Marking

<sup>1)</sup> Does not include plastic or metal protrusion of 0.15 max. per side

#### Layout Footprints





### CoreControl<sup>™</sup>

Data Sheet

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